

μ PG2430T6Z

Data Sheet

GaAs Integrated Circuit SP3T Switch for Bluetooth® and 802.11a/b/g R09DS0030EJ0100 Rev.1.00 Oct 24, 2011

DESCRIPTION

The μ PG2430T6Z is a GaAs MMIC SP3T switch which was developed for Bluetooth, wireless LAN. This device can operate at frequencies from 0.5 to 6.0 GHz, with low insertion loss and high isolation. This device is housed in a 8-pin plastic TSON (Thin Small Qut-line Non-leaded) package and is suitable for highdensity surface mounting.

FEATURES

Switch Control voltage : $V_{cont (H)} = 3.0 \text{ V TYP.}, V_{cont (L)} = 0 \text{ V TYP.}$

Low insertion loss : $L_{ins} = 0.55 \text{ dB TYP.} @ f = 2.5 \text{ GHz}$

: $L_{ins} = 0.65 \text{ dB TYP.}$ @ f = 6.0 GHz

High isolation : ISL = 28 dB TYP. @ f = 2.5 GHz

: ISL = 25 dB TYP. @ f = 6.0 GHz

: $P_{\text{in }(0.1 \text{ dB})} = +28.0 \text{ dBm TYP.}$ @ $V_{\text{cont }(H)} = 3.0 \text{ V}$, $V_{\text{cont }(L)} = 0 \text{ V}$ Handling power

High-density surface mounting : 8-pin plastic TSON package $(1.5 \times 1.5 \times 0.37 \text{ mm})$

APPLICATIONS

• Bluetooth and IEEE802.11a/b/g etc.

ORDERING INFORMATION

Part Number	Order Number	Package	Marking		Supplying Form
μPG2430T6Z-E2	μPG2430T6Z-E2-A	8-pin plastic	G6L	•	Embossed tape 8 mm wide
		TSON		•	Pin 1, 8 face the perforation side of the tape
		(Pb-Free)		•	Qty 3 kpcs/reel

Remark To order evaluation samples, please contact your nearby sales office.

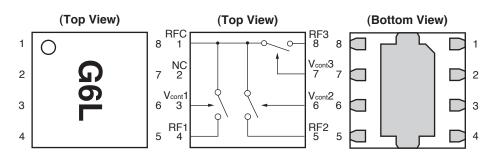
Part number for sample order: uPG2430T6Z-A



Although this device is designed to be as robust as possible, ESD (Electrostatic Discharge) can damage this device. This device must be protected at all times from ESD. Static charges may easily produce potentials of several kilovolts on the human body or equipment, which can discharge without detection. Industry-standard ESD precautions must be employed at all times.



PIN CONNECTIONS AND INTERNAL BLOCK DIAGRAM



Pin No.	Pin Name
1	RFC
2	NC Note
3	V _{cont} 1
4	RF1
5	RF2
6	V _{cont} 2
7	V _{cont} 3
8	RF3

Note: Non-Connection
Remark Exposed pad : GND

TRUTH TABLE

V _{cont} 1	V _{cont} 2	V _{cont} 3	RFC-RF1	RFC-RF2	RFC-RF3
High	Low	Low	ON	OFF	OFF
Low	High	Low	OFF	ON	OFF
Low	Low	High	OFF	OFF	ON

ABSOLUTE MAXIMUM RATINGS ($T_A = +25$ °C, unless otherwise specified)

Parameter	Symbol	Ratings	Unit
Switch Control Voltage	V_{cont}	+6.0 Note	V
Input Power (V _{cont (H)} = 3.0 V)	Pin	+32	dBm
Operating Ambient Temperature	T _A	-45 to +85	°C
Storage Temperature	T _{stg}	-55 to +150	°C

Note: $|V_{cont(H)} - V_{cont(L)}| \le 6.0 \text{ V}$

RECOMMENDED OPERATING RANGE $(T_A = +25^{\circ}C)$

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Operating Frequency	f	0.5	-	6.0	GHz
Switch Control Voltage (H)	V _{cont (H)}	1.6	3.0	3.6	V
Switch Control Voltage (L)	V _{cont (L)}	-0.2	0	0.2	V
Control Voltage Difference (H)	△V _{cont (H)} Note 1	-0.1	0	0.1	V
Control Voltage Difference (L)	△V _{cont (L)} Note 2	-0.1	0	0.1	V

Notes: 1. $\Delta V_{cont (H)}$ is a difference between the maximum and the minimum control voltages among $V_{cont}1_{(H)}$, $V_{cont}2_{(H)}$ and $V_{cont}3_{(H)}$.

2. $\Delta V_{cont \, (L)}$ is a difference between the maximum and the minimum control voltages among $V_{cont} 1_{\, (L)}$, $V_{cont} 2_{\, (L)}$ and $V_{cont} 3_{\, (L)}$.



ELECTRICAL CHARACTERISTICS 1 (T_A = +25°C, V_{cont (H)} = 3.0 V, V_{cont (L)} = 0 V, Z_O = 50 Ω , DC blocking capacitors = 8 pF, unless otherwise specified)

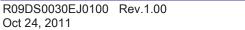
Parameter	Symbol	Path	Test Conditions	MIN.	TYP.	MAX.	Unit
Insertion Loss	L _{ins}	RFC to	f = 0.5 to 1.0 GHz Note 1	-	0.45	0.60	dB
		RF1, 2, 3	f = 1.0 to 2.0 GHz Note 1	-	0.45	0.60	dB
			f = 2.0 to 2.5 GHz	-	0.55	0.70	dB
			f = 2.5 to 4.9 GHz	_	0.60	0.80	dB
			f = 4.9 to 6.0 GHz	_	0.65	0.90	dB
Isolation	ISL	RFC to	f = 0.5 to 1.0 GHz Note 1	24	28	-	dB
		RF1, 2, 3	f = 1.0 to 2.0 GHz Note 1	24	28	-	dB
		(OFF)	f = 2.0 to 2.5 GHz	23	28	-	dB
			f = 2.5 to 4.9 GHz	23	28	-	dB
			f = 4.9 to 6.0 GHz	20	25	_	dB
Return Loss	RL		f = 0.5 to 1.0 GHz Note 1	-	23	-	dB
			f = 1.0 to 2.0 GHz Note 1	16	23	_	dB
			f = 2.0 to 2.5 GHz	16	23	-	dB
			f = 2.5 to 4.9 GHz	16	23	_	dB
			f = 4.9 to 6.0 GHz	10	23	_	dB
0.1 dB Loss Compression	P _{in (0.1 dB)}	RFC to	f = 2.5 GHz	+25.0	+28.0	_	dBm
Input Power Note 2		RF1, 2, 3	f = 6.0 GHz	+25.0	+28.0	_	dBm
1 dB Loss Compression	P _{in (1 dB)}	RFC to	f = 2.5 GHz	+28.0	+31.0	_	dBm
Input Power Note 3		RF1, 2, 3	f = 6.0 GHz	+28.0	+31.0	_	dBm
Input 3rd Order Intercept Point	IIP ₃		f = 2.5 GHz, 2 tone,	-	53	-	dBm
			5 MHz spacing				
2nd Harmonics	2f0		f = 2.5 GHz,	-	75	_	dBc
			P_{in} = +22 dBm				
3rd Harmonics	3f0		f = 2.5 GHz,	-	75	_	dBc
			P_{in} = +22 dBm				
Switch Control Current	I _{cont}		No RF input	-	0.1	5.0	μΑ
Switch Control Speed	t _{sw}		50% CTL to 90/10% RF	_	50	300	ns

Notes: 1. DC blocking capacitors = 56 pF at f = 0.5 to 2.0 GHz

- 2. $P_{in (0.1 dB)}$ is the measured input power level when the insertion loss increases 0.1 dB more than that of the linear range.
- 3. P_{in (1 dB)} is the measured input power level when the insertion loss increases 1 dB more than that of the linear range.

CAUTION

It is necessary to use DC blocking capacitors with this device.





ELECTRICAL CHARACTERISTICS 2 $(T_A = +25^{\circ}C, V_{cont (H)} = 1.8 \text{ V}, V_{cont (L)} = 0 \text{ V}, Z_O = 50 \Omega$, DC blocking capacitors = 8 pF, unless otherwise specified)

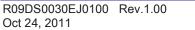
Parameter	Symbol	Path	Test Conditions	MIN.	TYP.	MAX.	Unit
Insertion Loss	L _{ins}	RFC to	f = 0.5 to 1.0 GHz Note 1	_	0.45	0.60	dB
		RF1, 2, 3	f = 1.0 to 2.0 GHz Note 1	_	0.45	0.60	dB
			f = 2.0 to 2.5 GHz	_	0.55	0.70	dB
			f = 2.5 to 4.9 GHz	_	0.60	0.80	dB
			f = 4.9 to 6.0 GHz	-	0.65	0.90	dB
Isolation	ISL	RFC to	f = 0.5 to 1.0 GHz Note 1	24	28	_	dB
		RF1, 2, 3	f = 1.0 to 2.0 GHz Note 1	24	28	-	dB
		(OFF)	f = 2.0 to 2.5 GHz	23	28	-	dB
			f = 2.5 to 4.9 GHz	23	28	_	dB
			f = 4.9 to 6.0 GHz	20	25	-	dB
Return Loss	RL		f = 0.5 to 1.0 GHz Note 1	-	23	-	dB
			f = 1.0 to 2.0 GHz Note 1	16	23	_	dB
			f = 2.0 to 2.5 GHz	16	23	_	dB
			f = 2.5 to 4.9 GHz	16	23	-	dB
			f = 4.9 to 6.0 GHz	10	23	_	dB
0.1 dB Loss Compression	P _{in (0.1 dB)}	RFC to	f = 2.5 GHz	+20.0	+23.0	_	dBm
Input Power Note 2		RF1, 2, 3	f = 6.0 GHz	+19.0	+22.0	_	dBm
1 dB Loss Compression	P _{in (1 dB)}	RFC to	f = 2.5 GHz	+24.0	+27.0	_	dBm
Input Power Note 3		RF1, 2, 3	f = 6.0 GHz	+22.0	+25.0	_	dBm
Input 3rd Order Intercept Point	IIP ₃		f = 2.5 GHz, 2 tone,	-	50	_	dBm
			5 MHz spacing				
2nd Harmonics	2f0		f = 2.5 GHz,	_	75	-	dBc
			P_{in} = +17 dBm				
3rd Harmonics	3f0		f = 2.5 GHz,	_	75	_	dBc
			P_{in} = +17 dBm				
Switch Control Current	I _{cont}		No RF input	_	0.1	5.0	μΑ
Switch Control Speed	tsw		50% CTL to 90/10% RF	ı	100	600	ns

Notes: 1. DC blocking capacitors = 56 pF at f = 0.5 to 2.0 GHz

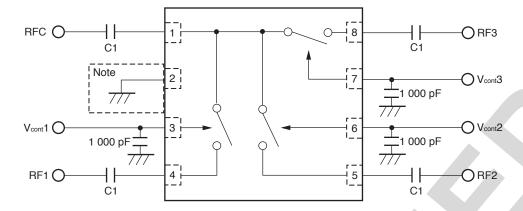
- 2. $P_{in (0.1 dB)}$ is the measured input power level when the insertion loss increases 0.1 dB more than that of the linear range.
- 3. P_{in (1 dB)} is the measured input power level when the insertion loss increases 1 dB more than that of the linear range.

CAUTION

It is necessary to use DC blocking capacitors with this device.



EVALUATION CIRCUIT

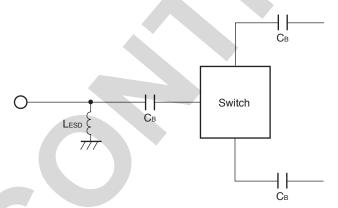


Note: It is recommended to connect the pin directly to the ground, or not to connect the pin to anything.

Remarks C1 : 0.5 to 2.0 GHz 56 pF : 2.0 to 6.0 GHz 8 pF

The application circuits and their parameters are for reference only and are not intended for use in actual design-ins.

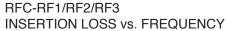
APPLICATION INFORMATION

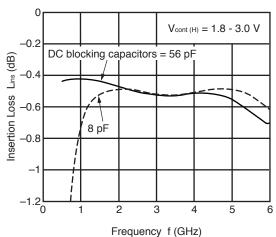


- C_B are DC blocking capacitors external to the device.
 A value of 8 pF is sufficient for operation from 2 GHz to 6 GHz bands.
 The value may be tailored to provide specific electrical responses.
- The RF ground connections should be kept as short as possible and connected to directly to a good RF ground for best performance.
- L_{ESD} provides a means to increase the ESD protection on a specific RF port, typically the port attached to the
 antenna.

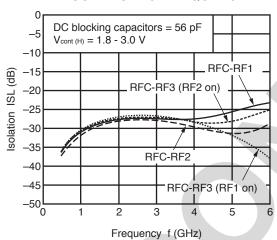
TYPICAL CHARACTERISTICS

 $(V_{cont (H)} = 3.0 \text{ V}, V_{cont (L)} = 0 \text{ V}, Z_O = 50 \Omega, DC blocking capacitors} = 8 pF, unless otherwise$ specified)

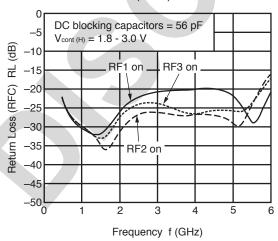


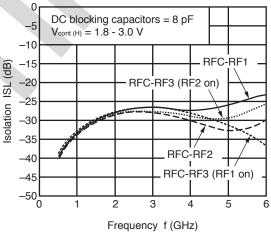


RFC-RF1/RF2/RF3 ISOLATION vs. FREQUENCY



RETURN LOSS (RFC) vs. FREQUENCY

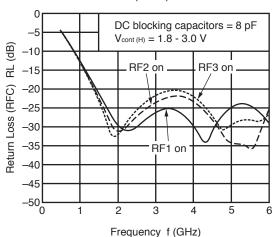




RFC-RF1/RF2/RF3

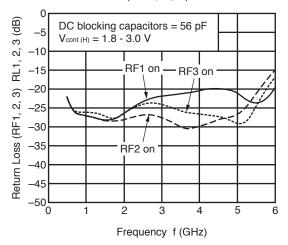
ISOLATION vs. FREQUENCY

RETURN LOSS (RFC) vs. FREQUENCY

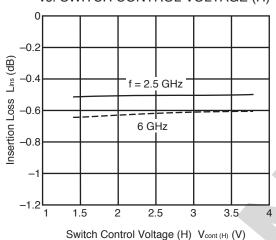


Remark The graphs indicate nominal characteristics.

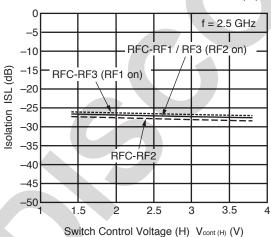
RETURN LOSS (RF1, 2, 3) vs. FREQUENCY



RFC-RF1/RF2/RF3 INSERTION LOSS vs. SWITCH CONTROL VOLTAGE (H)

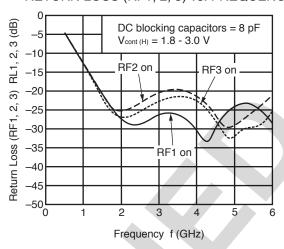


RFC-RF1/RF2/RF3 ISOLATION vs. SWITCH CONTROL VOLTAGE (H)

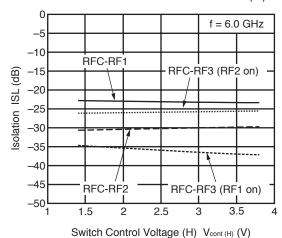


Remark The graphs indicate nominal characteristics.

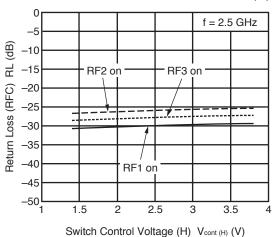
RETURN LOSS (RF1, 2, 3) vs. FREQUENCY



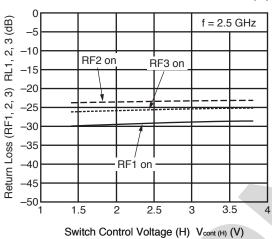
RFC-RF1/RF2/RF3 ISOLATION vs. SWITCH CONTROL VOLTAGE (H)



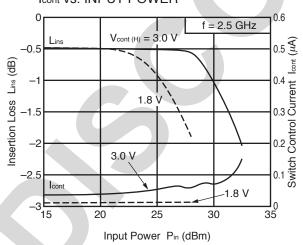
RETURN LOSS (RFC) vs. SWITCH CONTROL VOLTAGE (H)



RETURN LOSS (RF1, 2, 3) vs. SWITCH CONTROL VOLTAGE (H)

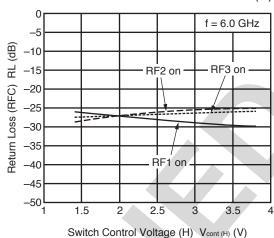


RFC-RF1/RF2/RF3 INSERTION LOSS, Icont vs. INPUT POWER

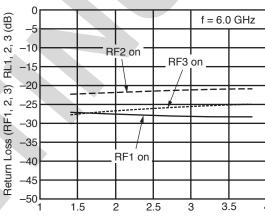


Remark The graphs indicate nominal characteristics.

RETURN LOSS (RFC) vs. SWITCH CONTROL VOLTAGE (H)

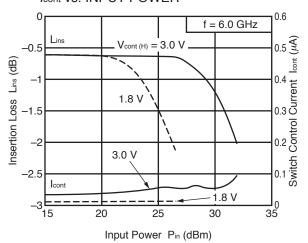


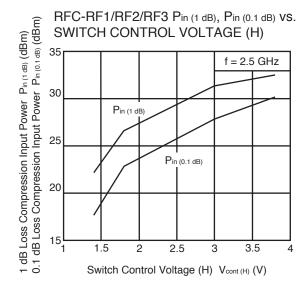
RETURN LOSS (RF1, 2, 3) vs. SWITCH CONTROL VOLTAGE (H)



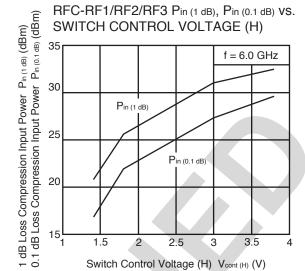
Switch Control Voltage (H) Vcont (H) (V)

RFC-RF1/RF2/RF3 INSERTION LOSS, Icont vs. INPUT POWER



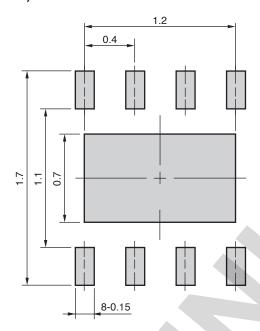


Remark The graphs indicate nominal characteristics.



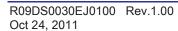
MOUNTING PAD LAYOUT DIMENSIONS

8-PIN PLASTIC TSON (UNIT: mm)



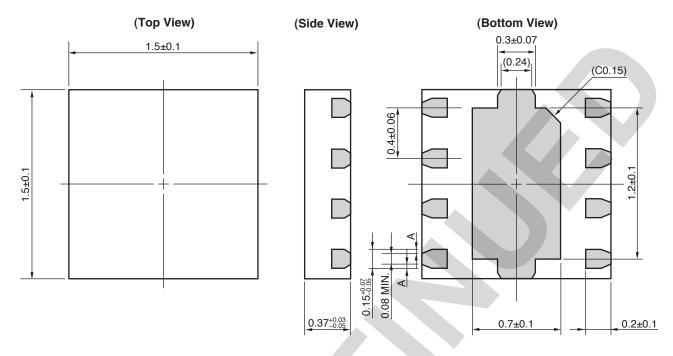
Remark The mounting pad layout in this document is for reference only.

When designing PCB, please consider workability of mounting, solder joint reliability, prevention of solder bridge and so on, in order to optimize the design.



PACKAGE DIMENSIONS

8-PIN PLASTIC TSON (UNIT: mm)



Remark A > 0
(): Reference value

RECOMMENDED SOLDERING CONDITIONS

This product should be soldered and mounted under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your nearby sales office.

Soldering Method	Soldering Conditions		Condition Symbol
Infrared Reflow	Peak temperature (package surface temperature)	: 260°C or below	IR260
	Time at peak temperature	: 10 seconds or less	
	Time at temperature of 220°C or higher	Time at temperature of 220°C or higher : 60 seconds or less	
	Preheating time at 120 to 180°C	: 120±30 seconds	
	Maximum number of reflow processes	: 3 times	
	Maximum chlorine content of rosin flux (% mass)	: 0.2% (Wt.) or below	
Partial Heating	Peak temperature (terminal temperature)	: 350°C or below	HS350
	Soldering time (per side of device)	: 3 seconds or less	
	Maximum chlorine content of rosin flux (% mass)	: 0.2% (Wt.) or below	

CAUTION

Do not use different soldering methods together (except for partial heating).



Caution

GaAs Products

This product uses gallium arsenide (GaAs).

GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.

- · Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
 - 1. Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
- 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
- Do not burn, destroy, cut, crush, or chemically dissolve the product.
- Do not lick the product or in any way allow it to enter the mouth.



Revision History

μ PG2430T6Z Data Sheet

		Description		
Rev.	Date	Page Summary		
1.00	Oct 24, 2011	-	First edition issued	



Bluetooth is a registered trademark owned by Bluetooth SIG, Inc., U.S.A.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for RF Switch ICs category:

Click to view products by CEL manufacturer:

Other Similar products are found below:

MASW-007921-002SMB BGSA142GN12E6327XTSA1 BGSA142MN12E6327XTSA1 BGSA142M2N12E6327XTSA1 MASW-00410011930W MASW-008853-TR3000 BGS13SN8E6327XTSA1 BGSF18DM20E6327XUMA1 BGSX210MA18E6327XTSA1

BGSX212MA18E6327XTSA1 SKY13446-374LF SW-227-PIN PE42524A-X CG2185X2 CG2415M6 MA4AGSW1A MA4AGSW2

MA4AGSW3 MA4AGSW5 MA4SW210B-1 MA4SW410 MASW-002102-13580G BGS 12PL6 E6327 BGS1414MN20E6327XTSA1

BGS1515MN20E6327XTSA1 BGSA11GN10E6327XTSA1 BGSX28MA18E6327XTSA1 HMC199AMS8 HMC595AETR HMC986A

SKY13374-397LF SKY13453-385LF CG2430X1-C2 TGS4304 UPG2162T5N-A CG2415M6-C2 AS222-92LF SW-314-PIN

UPG2162T5N-E2-A BGS18GA14E6327XTSA1 MASWSS0204TR-3000 MASWSS0201TR MASWSS0181TR-3000 MASW-007588
TR3000 MASW-007075-000100 MASW-004103-13655P MASW-003102-13590G MASWSS0202TR-3000 MASW-008543-TR3000

MA4SW310B-1